

**200CNQ035/200CNQ040/200CNQ045  
SCHOTTKY RECTIFIER**

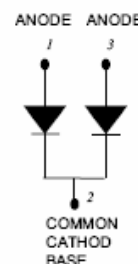
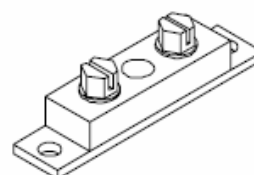
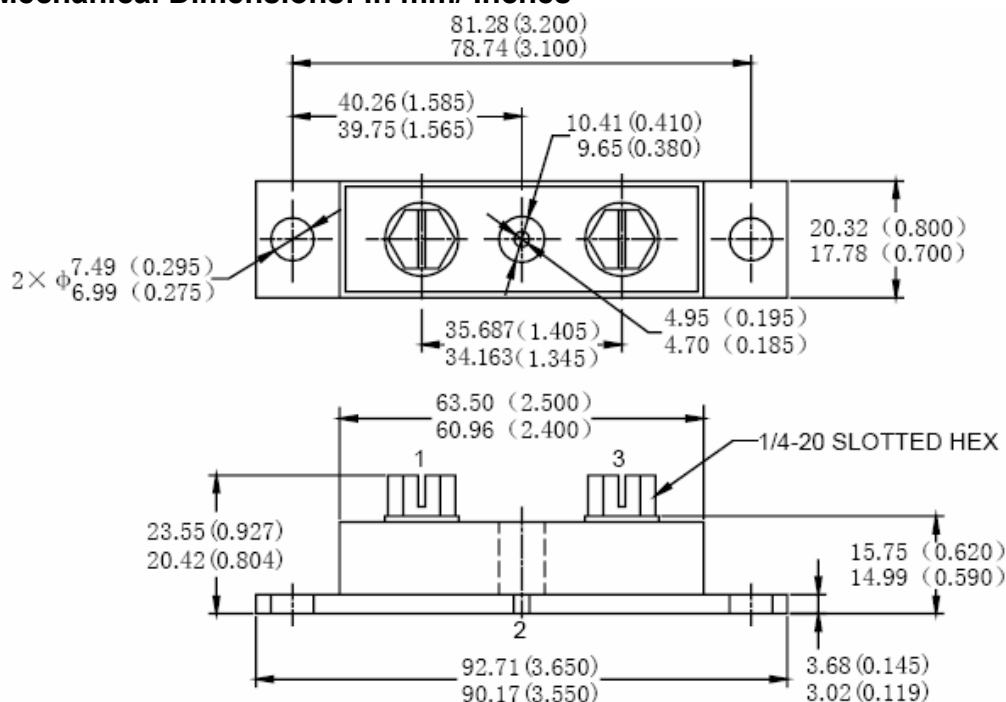
**Applications:**

- High current switching power supply • Plating power supply • Free-Wheeling diodes
- Reverse battery protection • Converters • UPS System • Welding

**Features:**

- 150 °C T<sub>J</sub> operation
- Center tap module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

**Mechanical Dimensions: In mm/ Inches**



**PRM4 (Non-Isolated)**

**MARKING, MOLDING RESIN**

Marking for 200CNQ035/040/045, 1<sup>st</sup> row SS YYWWL, 2<sup>nd</sup> row 200CNQ035/040/045  
Where YY is the manufacture year  
WW is the manufacture week code  
L is the wafer's Lot Number

Molding resin

Epoxy resin UL:94V-0

**Technical Data**  
**Data Sheet N1185, Rev. B**
**Green Products**
**Maximum Ratings:**

Characteristics	Symbol	Condition	Max.		Units
Peak Inverse Voltage	$V_{RWM}$	-	35	200CNQ035	V
			40	200CNQ040	
			45	200CNQ045	
Max. Average Forward	$I_{F(AV)}$	50% duty cycle @ $T_C=114^{\circ}C$ , rectangular wave form	100	per leg	A
			200	per device	
Max. Peak One Cycle Non-Repetitive Surge Current (per leg)	$I_{FSM}$	8.3 ms, half Sine pulse	1860		A
Non-Repetitive Avalanche Energy(peg leg)	$E_{AS}$	$T_J=25^{\circ}C, I_{AS}=20A, L=0.67mH$	135		mJ
Repetitive Avalanche Current(peg leg)	$I_{AR}$	Current decaying linearly to zero in 1 $\mu$ sec Frequency limited by $T_J$ max. $V_A=1.5 \times V_R$ typical	20		A

**Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg) *	$V_{F1}$	@ 100A, Pulse, $T_J = 25^{\circ}C$	0.57	V
		@ 200A, Pulse, $T_J = 25^{\circ}C$	0.72	
Max. Reverse Current (per leg) *	$V_{F2}$	@ 100A, Pulse, $T_J = 125^{\circ}C$	0.49	V
		@ 200A, Pulse, $T_J = 125^{\circ}C$	0.64	
Max. Reverse Current (per leg) *	$I_{R1}$	@ $V_R =$ rated $V_R$ $T_J = 25^{\circ}C$	10	mA
	$I_{R2}$	@ $V_R =$ rated $V_R$ $T_J = 125^{\circ}C$	500	mA
Max. Junction Capacitance (per leg)	$C_T$	@ $V_R = 5V, T_C = 25^{\circ}C$ $f_{SIG} = 1MHz$	5200	pF
Typical Series Inductance (per leg)	$L_S$	Measured lead to lead 5 mm from package body	7.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/ $\mu$ s

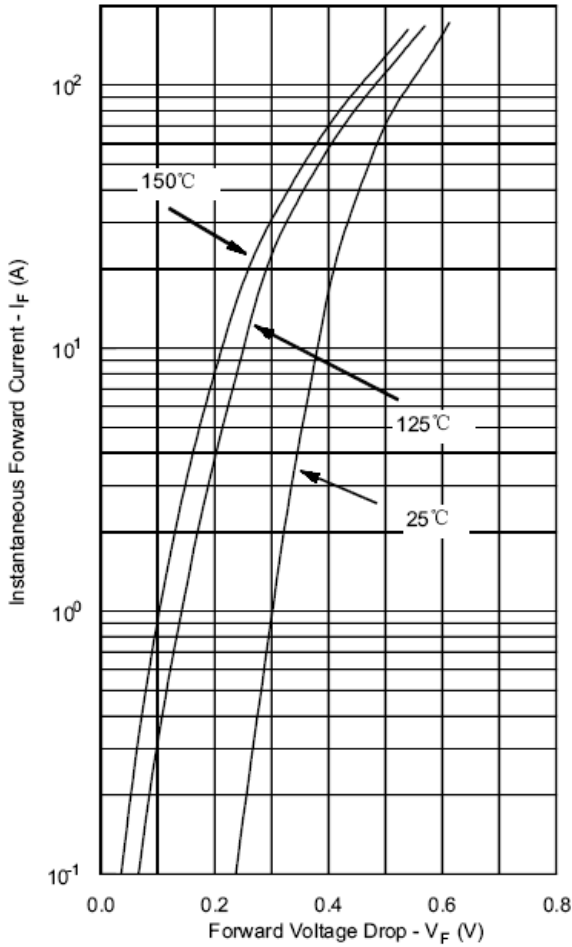
\* Pulse Width < 300 $\mu$ s, Duty Cycle <2%

**Thermal-Mechanical Specifications:**

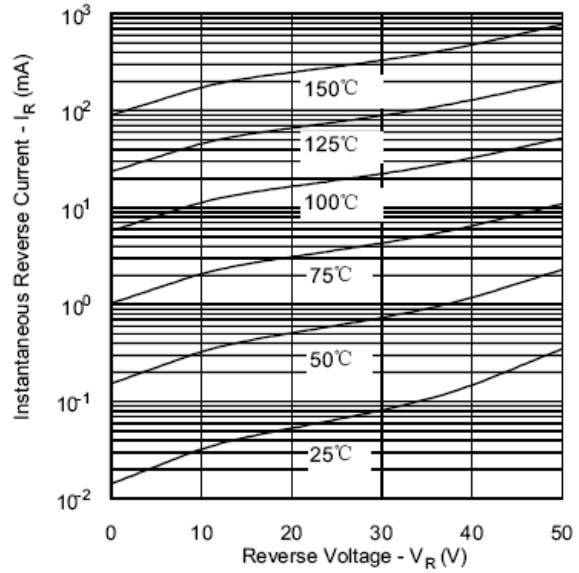
Characteristics	Symbol	Condition	Specification		Units
Max. Junction Temperature	$T_J$	-	-55 to +150		$^{\circ}C$
Max. Storage Temperature	$T_{stg}$	-	-55 to +150		$^{\circ}C$
Maximum Thermal Resistance Junction to Case (per leg)	$R_{\theta JC}$	DC operation	0.50		$^{\circ}C/W$
Maximum Thermal Resistance Junction to Case (per package)	$R_{\theta JC}$	DC operation	0.25		$^{\circ}C/W$
Typical Thermal Resistance, case to Heat Sink	$R_{\theta cs}$	Mounting surface, smooth and greased	0.10		$^{\circ}C/W$
Mounting Torque	$T_M$	-	Mounting Torque	24(min) 35(max)	Kg-cm
			Terminal Torque	35(min) 46(max)	
Approximate Weight	wt	-	79		g
Case Style	PRM4 Non-Isolated				

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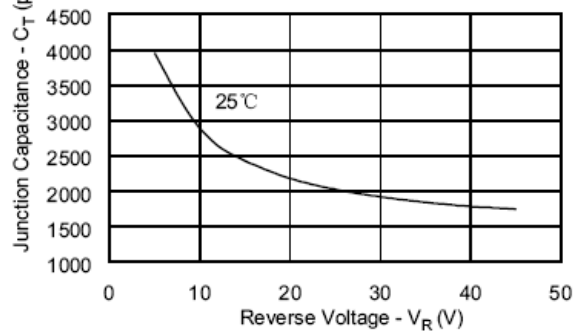
**Typical Forward Characteristics**



**Typical Reverse Characteristics**



**Typical Junction Capacitance**



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